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BC847BS

February 2013

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### **DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR**

### **Features**

- Ultra-Small Surface Mount Package
- Ideally Suited for Automated Insertion
- For switching and AF Amplifier Application
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

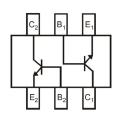
### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.006 grams (approximate)

**SOT363** 



Top View



Device Schematic Top View

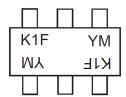
### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC847BS-7-F	AEC-Q101	K1F	7	8	3,000
BC847BSQ-7-F	Automotive	K1F	7	8	3,000
BC847BS-13-F	AEC-Q101	K1F	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



K1F = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

Year	2010	201	1	2012	20	13	2014	2	2015	2016		2017
Code	Χ	Y		Z		A	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Maximum Ratings** (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	$V_{CEO}$	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	Ic	100	mA
Peak Collector Current	I <sub>CM</sub>	200	mA
Peak Base Current	I <sub>BM</sub>	200	mA

## 

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	$P_D$	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## Electrical Characteristics (@TA = +25°C unless otherwise specified.)

Characteristic (Note 7)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	50	1	l	V	$I_C = 100 \mu A, I_B = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	45			V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	$BV_{EBO}$	6	-	l	V	$I_E = 100 \mu A, I_C = 0$
DC Current Gain	h <sub>FE</sub>	200		450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	V	-	_	100 400	mV	$I_C = 10mA, I_B = 0.5mA$
Collector-Emitter Saturation voltage	V <sub>CE(sat)</sub>					$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	755		mV	$I_C = 10mA$ , $I_B = 0.5mA$
Base-Emitter Voltage	$V_{BE(on)}$	580	665	700	mV	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Cutoff Current	lone		1	20	nA	V <sub>CB</sub> = 40V
Collector-Cutoff Current	I <sub>CBO</sub>	_	1	5.0	μA	V <sub>CB</sub> = 40V, T <sub>A</sub> = +125°C
Emitter-Cutoff Current	I <sub>EBO</sub>	_	1	100	nA	$V_{EB} = 5.0V, I_{C} = 0$
Gain Bandwidth Product	f <sub>T</sub>	100	1	-	MHz	$V_{CE} = 5.0V, I_{C} = 10mA,$ f = 100MHz
Collector-Base Capacitance	Ссво	_	2.0	3.0	pF	V <sub>CB</sub> = 10V, f = 1.0MHz
Emitter-Base Capacitance	C <sub>EBO</sub>	_	11	_	pF	V <sub>EB</sub> = 0.5V, f = 1.0MHz

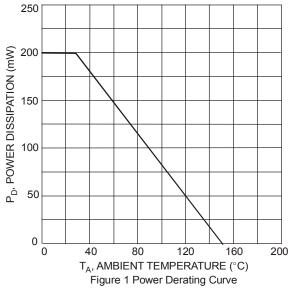
Notes:

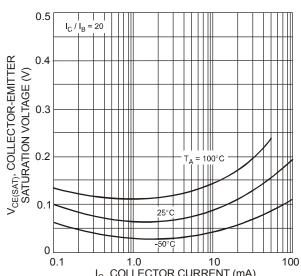
<sup>6.</sup> For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

7. Short duration pulse test used to minimize self-heating effect.



## Typical Electrical Characteristics (@TA = +25°C unless otherwise specified.)





0.1 1.0 10 10 10 10 I<sub>C</sub>, COLLECTOR CURRENT (mA)
Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

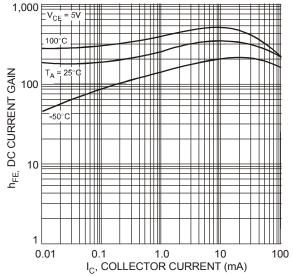


Figure 2 Typical DC Current Gain vs. Collector Current

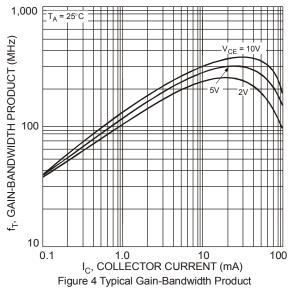
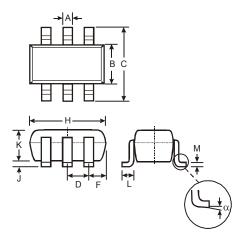


Figure 4 Typical Gain-Bandwidth Product vs. Collector Current



## **Package Outline Dimensions**

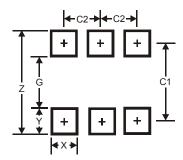
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT363						
Dim	Min	Max	Тур				
Α	0.10	0.30	0.25				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	0.65 Typ						
F	0.40	0.45	0.425				
Н	1.80	2.20	2.15				
J	0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.22	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Υ	0.6
C1	1.9
C2	0.65

February 2013

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